

Variable electrostatic transformer: controllable coupling of two charge qubits

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We propose and investigate a novel method for the controlled coupling of two Josephson charge qubits by means of a variable electrostatic transformer. The value of the coupling capacitance is given by the discretized curvature of the lowest energy band of a Josephson junction, which can be positive, negative, or zero. We calculate the charging diagram of the two-qubit system that reflects the transition from positive to negative through vanishing coupling. We also discuss how to construct a phase gate making use of the controllable coupling.

Following experimental demonstrations of individual qubits implemented with Josephson junctions operated in the charge [1,2] or flux [3–5] regimes, a great deal of interest is now focused on the question of how to build multi-qubit circuits of Josephson junctions. Recently, there has been an encouraging first experimental step [6] in this direction demonstrating quantum-coherent dynamics of two charge qubits coupled directly through a capacitance. The coupling strength of the two qubits in this experiment could not be varied, since there is no simple way of changing the electrostatic capacitance between two metallic islands. This experiment underlined the desirability of having controlled coupling of charge qubits. Many two-qubit transformations that could be implemented if the coupling is controlled become much more difficult or impossible at constant coupling, since in the presence of interactions one needs to correct for different dynamic phases of the two-qubit states.

For flux qubits, the problem of a controlled qubit coupling can be solved with variable flux transformers (see, e.g., [7]) which can be implemented naturally with the standard tools of superconductor electronics [8]. For other types of “magnetic” qubits, e.g., spin qubits, the possibility to control the qubit coupling both in sign and absolute value has been predicted theoretically [9] (for recent experimental progress, see [10]). For charge qubits, however, a comparably natural solution has been lacking although the importance of the interaction control problem has been recognized for quite some time. Suggested controlled coupling methods include direct spatial separation of qubit states by adiabatic transfer along junction arrays [11] or coupling through superconducting resonators [12–18]. The first one is too complicated to be practical, at least presently. The second requires inductances of relatively large value and small geometric dimension that are fundamentally difficult to produce, in particular without creating additional dissipation at the relevant large frequencies.

The purpose of this work is to propose and study a new circuit that should make it possible to implement a controllable coupling of charge qubits. The circuit, shown in

Fig. 1, generalizes the simple capacitive coupling used in [6] and makes use of the following basic feature of an individual small Josephson tunnel junction. If the junction dynamics is confined to the lowest energy band of the band structure, it behaves as a variable capacitance with respect to the charge injected into the junction [19]. The magnitude of this capacitance depends on the bias point and can even be made *negative*. This fact is important for the application as a controllable coupling element, since it enables one to drive the coupling capacitance to zero by choosing an appropriate bias point. The physics of the capacitance modulation is the transformation of charge, when an injected charge causes a Cooper-pair transfer across the junction that changes the output charge. If, however, the two qubits are coupled directly through a small junction (the coupling scheme considered, e.g., in a somewhat different context in [20]) this mechanism would not produce a variable-coupling scheme, since variations of the junction capacitance are compensated by a redistribution of the transferred charge on the capacitances in series with the junction. Nevertheless, a modification of this approach in which the junction is included “perpendicular” to the coupling direction, as in Fig. 1, produces the required “variable electrostatic transformer” with a gate-voltage-controlled coupling capacitance.

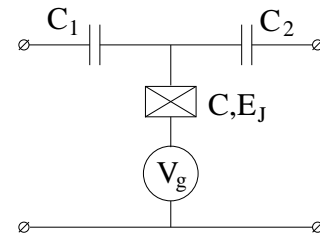


FIG. 1. Equivalent circuit of the variable electrostatic transformer for the controlled coupling of charge qubits. The Josephson coupling energy E_J of the small tunnel junction and the capacitances C , C_1 , C_2 of the structure determine the dispersion relation of the junction. Its lowest energy band $\epsilon_0(q)$ provides the required variable coupling capacitance controlled by the gate voltage V_g .

Indeed, if the voltage V is applied to the pair of input

terminals (left or right, $i = 1, 2$) of the circuit shown in Fig. 1, the Hamiltonian of the system is that of an individual Josephson junction (or “Cooper-pair box” [21,22]) with the charge $q + q_g$ injected into it, where $q_g = C_i V_g$ and $q = C_i V$. This implies that when the junction is in its lowest energy band ϵ_0 , the output voltage V_{out} at the opposite terminals varies such that

$$C_0 \equiv \partial V_{out} / \partial q = \partial^2 \epsilon_0(q_g + q) / \partial q^2. \quad (1)$$

The coupling capacitance C_0 defined by this relation varies with the charge q_0 injected by the gate voltage and goes through zero at a bias point dependent on the shape of the energy band $\epsilon_0(q)$.

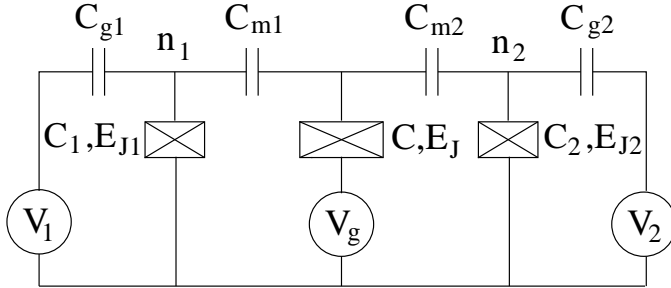


FIG. 2. Equivalent circuit of the two charge qubits coupled by a variable electrostatic transformer.

If the transformer shown in Fig. 1 is inserted between two charge qubits (Fig. 2), it provides a gate-voltage-controlled qubit coupling. The qubits 1,2 with Josephson coupling energies E_{Ji} , $i = 1, 2$, are biased by the gate voltages V_i through the capacitances C_{gi} and are coupled to the central island of the transformer by capacitances C_{mi} . Inverting the capacitance matrix of this system, we can write the Hamiltonian as

$$H = - \sum_{i=1,2} E_{Ji} \cos \varphi_i + E_{Ci} (n_i - q_i)^2 - E_J \cos \varphi + E_C (n - q(n_1, n_2))^2, \quad (2)$$

where $E_C = 2e^2 / (C_\Sigma - \sum_i C_{mi}^2 / C_{\Sigma i})$, $E_{Ci} = 2e^2 / C_{\Sigma i}$, and $q_i \equiv V_i C_{gi} / 2e$. The qubits are coupled through the charge q induced on the transformer junction: $q = q_g - \sum_i (n_i - q_i) C_{mi} / C_{\Sigma i}$, where $q_g \equiv (V_g / 2e) \sum_i C_{mi} (1 - C_{mi} / C_{\Sigma i})$. The Josephson phase differences across the respective junctions are denoted by φ_i and φ . Finally, $C_{\Sigma i} \equiv C_i + C_{gi} + C_{mi}$, and $C_\Sigma \equiv C + C_{m1} + C_{m2}$.

We assume that the degrees of freedom of the transformer junction are fast, and that the junction is confined to the lowest energy band of its band structure. Then we can replace the part of the Hamiltonian related to the transformer by the dispersion relation $\epsilon_0(q)$ of this lowest band,

$$-E_J \cos \varphi + E_C (n - q(n_1, n_2))^2 \rightarrow \epsilon_0(q(n_1, n_2)). \quad (3)$$

This is the analogue of the Born-Oppenheimer approximation which in our case is valid if the characteristic

energy gap between the bands of the transformer junction is much larger than the qubit energies. For our qubit coupling, this condition requires that $E_J \gg E_{Ji}$.

To find the properties of the qubit coupling provided by the transformer we will use the known properties of the junction bandstructure [19,23]. Also, we use the fact that in the charge qubit regime ($E_{Ji} \ll E_{Ci}$, $q_i \simeq 1/2$), the dynamics of the charges n_i in (2) is reduced to a two-state dynamics, so that the charges can be expressed through the Pauli matrices, $n_i = (\sigma_{zi} + 1)/2$. Assuming that the structure in Fig. 2 is symmetric, i.e., $C_{m1}/C_{\Sigma 1} = C_{m2}/C_{\Sigma 2} \equiv c$ and using the properties of the Pauli matrices, the transformer term $\epsilon_0(q(n_1, n_2))$ in the reduced Hamiltonian can be expressed as follows:

$$\epsilon_0(q(n_1, n_2)) = \nu \sigma_{z1} \sigma_{z2} + \delta (\sigma_{z1} + \sigma_{z2}) + \mu. \quad (4)$$

For the coupling coefficient ν we obtain the following explicit expression:

$$\nu = \frac{1}{4} [\epsilon_0(q_0 + c) + \epsilon_0(q_0 - c) - 2\epsilon_0(q_0)], \quad (5)$$

where $q_0 = q_g + c \sum_i (q_i - 1/2)$. The term linear in σ_z shifts the qubit bias by $\delta = [\epsilon_0(q_0 + c) - \epsilon_0(q_0 - c)]/4$, and the constant term $\mu = [\epsilon_0(q_0 - c) + \epsilon_0(q_0 + c) + 2\epsilon_0(q_0)]$ is not relevant as long as we are discussing one pair of qubits.

Equation 5 is one the central results of our work. We see that ν has the structure of a discretized second derivative of ϵ_0 similarly to Eq. 1. Since $\epsilon_0(q)$ is a periodic function, ν can be positive or negative. For instance, in the tight-binding limit $E_C \ll E_J$, when $\epsilon_0(q) = -\Delta \cos(2\pi q)$, the coupling is:

$$\nu = \frac{\Delta}{2} \cos(2\pi q_0) (1 - \cos(2\pi c)), \quad (6)$$

and $\delta = (\Delta/2) \cos(2\pi q_0) \cos(2\pi c)$. Obviously, the coupling can be controlled by the gate voltage through the average induced charge q_0 , and can change sign. In general, the coupling constant can be calculated numerically from Eq. 5. The results are plotted in Fig. 3 which shows that in accordance with Eq. 6, the q_0 -dependence of ν is harmonic for $E_C \leq E_J$, and changes sign at $q_0 \approx \pm 1/4$. At larger E_C , $\nu(q_0)$ becomes non-harmonic, and for $E_C \gg E_J$ and small coupling coefficients c , approaches $c^2 E_C / 2$ for all q_0 except for the vicinity of the point $q_0 = \pm 1/2$, where $\nu/c^2 E_C$ becomes large in absolute value and negative: $\nu/c^2 E_C \simeq -E_C / 2E_J$. The periodic nature of $\epsilon_0(q)$ which has a minimum at $q = 0$ and a maximum at $q = \pm 1/2$ implies that the maximum of the absolute value of ν is reached for $c = 1/2$ and is equal to half the bandwidth, e.g., $E_C / 8$ for $E_C \gg E_J$.

The controlled electrostatic coupling of two qubits offers new possibilities to manipulate two-qubit states. The simplest one is the change of the structure of the *charging diagram* of the transformer-coupled qubits with the

gate voltage V_g . The charging diagram shows the regions of stability of the charge states (n_1, n_2) as a function of the induced charges $q_i \equiv V_i C_{gi}/2e$, $i = 1, 2$, for small Josephson coupling $E_{Ji} \ll E_{Ci}$. The diagram is periodic with period 1 in both charges q_i , and has a honeycomb structure in the case of fixed electrostatic coupling (see, e.g., [6]). The charging diagram of two qubits coupled through the variable transformer is shown in Fig. 4 for several values of the gate charge q_g on the transformer island. The main qualitative features of the diagram can be understood from the q_0 -dependence of the qubit interaction illustrated in Fig. 3, which shows that the maximum of the negative qubit coupling occurs for $q_0 \simeq \pm 0.5$, and the coupling becomes increasingly more positive if q_0 moves away from this point.

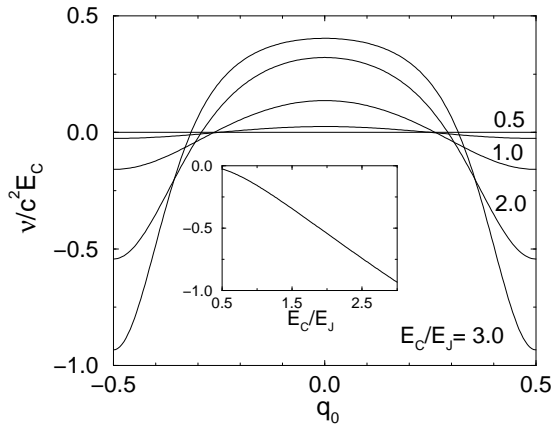


FIG. 3. Coupling energy ν of the two qubits in units of the charging energy E_C of the transformer junction as a function of the average charge q_0 induced on this junction. The coupling strength is $c = 0.1$, and the ratio E_C/E_J is given for each curve. The normalization of ν by c^2 makes it qualitatively independent of c for small c . Inset: $\nu(q_0)$ at $q_0 = \pm 0.5$, as a function of E_C/E_J for the same coupling strength c .

At the relatively small coupling strength $c = 0.3$ chosen in Fig. 4, the difference between $q_0 = q_g + c \sum_i (q_i - 1/2)$ and q_g is not essential for our qualitative discussion. For $q_g = 0$, the coupling is positive and the charging diagram has the usual shape characteristic of a fixed electrostatic coupling. The cells of the honeycomb structure are tilted in the $q_1 = -q_2$ direction, since increasing the gate voltage of one qubit makes it easier to add a charge to the other qubit. Consistent with this, the degeneracy point of the four charge states $(0, 0)$, $(0, 1)$, $(1, 0)$, $(1, 1)$ in the absence of coupling is extended in the $q_1 = q_2$ direction into the boundary between the two states $(0, 1)$, $(1, 0)$, since positive coupling makes the charging energy of these two states lower than that of $(0, 0)$ and $(1, 1)$ which now do not touch any more in the diagram. If the coupling is mostly negative, e.g., for $q_g = -0.5$, the cells of the honeycomb structure are tilted in the $q_1 = q_2$ direction. The degeneracy point of the four charge states is changed differently, since the states $(0, 0)$ and $(1, 1)$ now have a

lower charging energy than $(0, 1)$, $(1, 0)$. The degeneracy point is extended in the $q_1 = -q_2$ direction and creates a direct boundary between the $(0, 0)$ and $(1, 1)$ states. For $q_g = 0.25$ (Fig. 4), the qubit coupling is suppressed, and the $(0, 0)$ stability region approaches the rectangular shape characteristic of non-interacting qubits. In contrast to the case of fixed coupling, however, the cells in Fig. 4 are curved, since changing q_1, q_2 also changes the effective charge q_0 of the transformer island, so that the effective qubit coupling constant ν and the renormalization δ of the qubit bias change with q_i . This effect is largest for values of q_g around which $\nu(q_0)$ varies strongly, like e.g., $q_g = -0.4$, see Figs. 3 and 4.

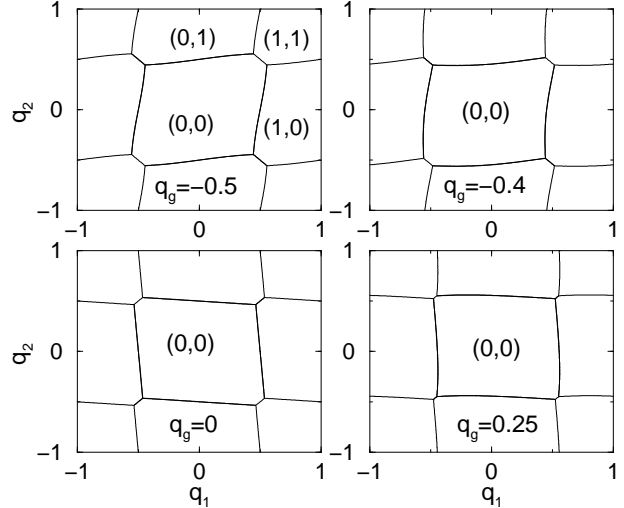


FIG. 4. Charging diagram of two charge qubits coupled through the variable electrostatic transformer for $c = 0.3$ and $E_C/E_J = 3$. The curves show the boundaries of the stability regions of the charge states (n_1, n_2) in the plane of the two induced charges $q_i \equiv V_i C_{gi}/2e$, $i = 1, 2$. The gate charge q_g is controlled by the transformer gate voltage V_g . The changing shape of the stability region reflects the V_g -controlled transition from positive to negative effective coupling capacitance of the two qubits.

The possibility to switch the coupling between two qubits on and off is essential for the realization of practically all types of two-qubit gates. An advantage of our scheme is that the effective qubit coupling can be suppressed even in presence of a small direct positive geometric capacitance between the qubit islands. This “parasitic” capacitance only shifts the values of the gate voltages at which the total coupling vanishes. As an example, we show how our proposal can be used to directly realize a *phase gate*, a transformation that changes the sign of the $|11\rangle$ state and does not change the amplitudes of the other three two-qubit states. If the qubit tunneling amplitudes are tuned to zero, the Hamiltonian of the two-qubit system (Fig. 2) with coupling (4) is

$$H = \nu \sigma_{z1} \sigma_{z2} + \eta (\sigma_{z1} + \sigma_{z2}), \quad (7)$$

where $\eta = \delta - E_{Ci}(q_i - 1/2)$. (For simplicity, we again dis-

cuss only the symmetric structure, which for the purpose of realizing the phase gate also implies identical qubit charges q_i . All results of our work can be directly extended to the asymmetric case.) By adjusting the three gate voltages V_1 , V_2 , and V_g such that $\nu(q_0 = q^*) = 0$ and $q_i = 1/2 + \delta(q^*)/E_{Ci}$ one can make the Hamiltonian (7) vanish. For $E_J \ll E_C$ such a stationary qubit state is realized when $q_i = 1/2$ and $q_0 = q_g = 1/4$. By applying gate-voltage pulses one can temporarily switch on both the interaction and the qubit bias in such a way that the qubit states accumulate dynamic phases [24]. To obtain a phase gate, i.e., to have the state $|11\rangle$ accumulate the phase π up to an irrelevant common phase of all four qubit states, the phase $\phi_\nu = \int dt \nu(t)$ due to the interaction energy and the phase $\phi_\eta = \int dt \eta(t)$ due to the qubit bias should be chosen as $\phi_\nu = \phi_\eta = \pi/4$.

These conditions fix only the time integral of the gate-voltage pulses. Their shape is arbitrary and can be chosen to reduce the excitation amplitude of the upper energy band of the transformer junction that would invalidate our Born-Oppenheimer approximation (3) and effectively entangle the qubit states with the states of the transformer creating an additional decoherence mechanism. Transitions to the upper energy bands are suppressed if the pulses are sufficiently slow on the scale of the transformer energies. In this case, the amplitude $\alpha_k(t)$ of an excitation process to the k th band can be calculated by standard adiabatic perturbation theory as

$$\alpha_k = \int^t d\tau \frac{\langle k | \partial H / \partial \tau | 0 \rangle}{\epsilon_k(\tau)} e^{-i \int_\tau^t \epsilon_k(\tau') d\tau'}, \quad (8)$$

where ϵ_k is the energy of the k th band relative to ϵ_0 . Since the total phases accumulated by the qubit states during the gate-voltage pulses are of the order of π , the adiabatic condition also means that the pulse amplitude should be small, i.e., $q_0 = q^* + x(t)$, $x \ll 1$. Therefore, the energies and matrix elements in Eq. 8 can be evaluated at $q_0 = q^*$, and Eq. 8 reduces to

$$|\alpha_k| = 2E_C |\langle k | (n - q) | 0 \rangle| |x(\epsilon_k)|. \quad (9)$$

Here, $x(\epsilon_k) = \int d\tau x(\tau) e^{i\epsilon_k \tau}$ is the Fourier component of $x(t)$ which decreases exponentially in $\epsilon_k \tau_0$ for smooth pulses, where τ_0 is the characteristic pulse time. Since the minimum of the energy-band separation ϵ_k is equal to E_J , this energy sets a lower limit for the pulse time through Eq. 9.

In conclusion, we have proposed a method to couple two Josephson charge qubits by an electrostatic transformer that produces an effective coupling that can be varied in magnitude and sign. We have given an explicit expression of this coupling as a discretized second derivative of the energy band of a small Josephson junction. An advantage of our proposal is that it works even for asymmetric structures and in the presence of parasitic capacitances. It allows the construction of a variety

of two-qubit gates, and we have explicitly demonstrated how to build a phase gate.

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